

TC74ACT280P, TC74ACT280F, TC74ACT280FN

9-Bit Parity Generator/Checker

The TC74ACT280 is an advanced high speed CMOS 9-BIT PARITY GENERATOR fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The TC74ACT280 is composed of nine data inputs (A thru I) and odd/even parity outputs (Σ ODD and Σ EVEN).

The odd parity output is high when an odd number of data inputs are high. The even parity output is high when an even number of data inputs are high.

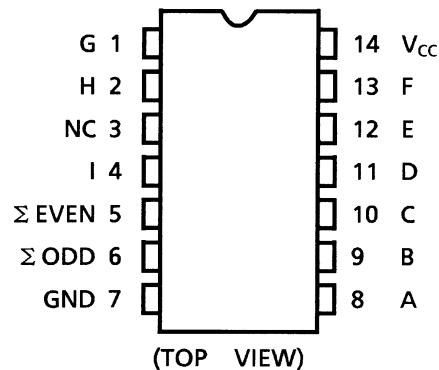
The word-length capability is easily expanded by cascading.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

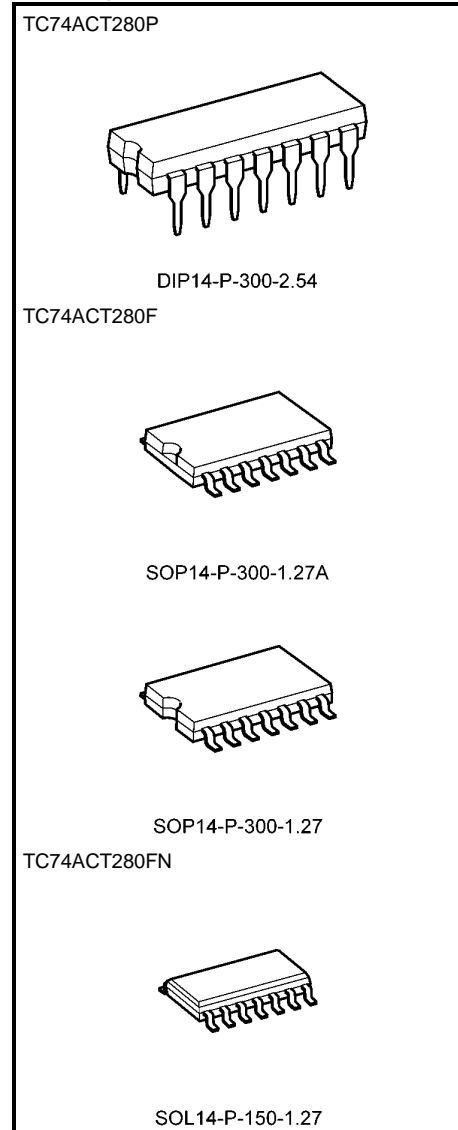
- High speed: $t_{pd} = 9.2$ ns (typ.) at $V_{CC} = 5$ V
- Low power dissipation: $I_{CC} = 8$ μ A (max) at $T_a = 25^\circ$ C
- Compatible with TTL outputs: $V_{IL} = 0.8$ V (max)
 $V_{IH} = 2.0$ V (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min)
Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F280

Pin Assignment



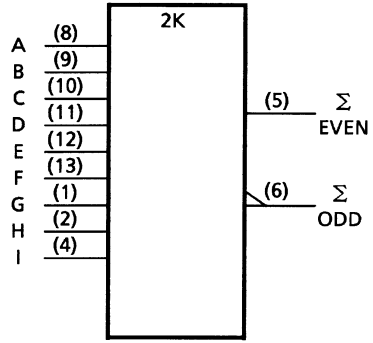
NC: No connection

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight	
DIP14-P-300-2.54	: 0.96 g (typ.)
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)

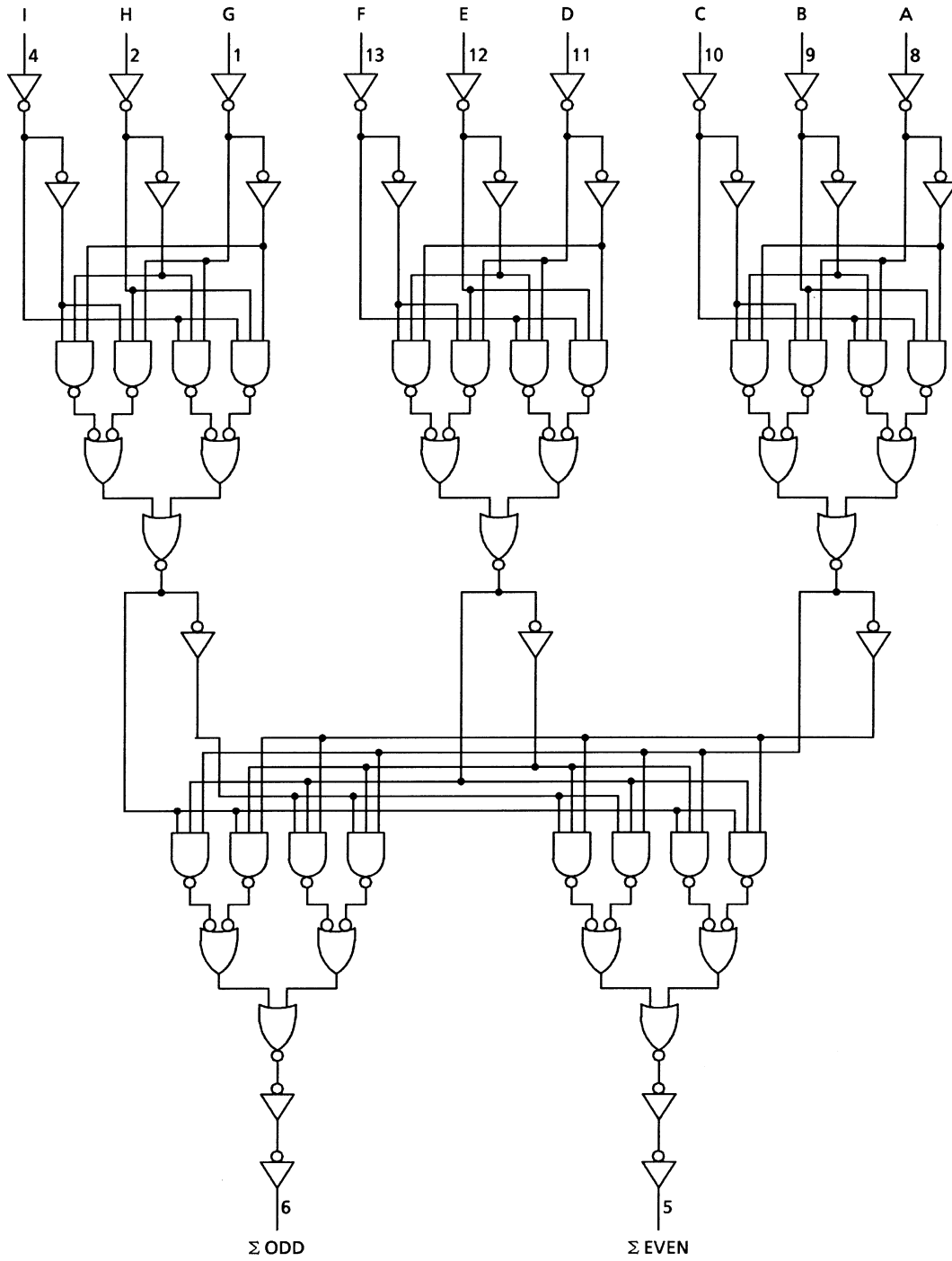
IEC Logic Symbol



Truth Table

Number of Inputs A Through I That are High	Outputs	
	Σ EVEN	Σ ODD
0, 2, 4, 6, 8	H	L
1, 3, 5, 7, 9	L	H

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 50	mA
DC output current	I_{OUT}	± 50	mA
DC V_{CC} /ground current	I_{CC}	± 100	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of $T_a = -40$ to $65^{\circ}C$. From $T_a = 65$ to $85^{\circ}C$ a derating factor of -10 mW/ $^{\circ}C$ should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5 to 5.5	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	$^{\circ}C$
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V _{IL}	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5	—	4.4	—	V
			I _{OH} = -24 mA	4.5	3.94	—	—	3.80	—	
			I _{OH} = -75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I _{OL} = 24 mA	4.5	—	—	0.36	—	0.44	
			I _{OL} = 75 mA (Note)	5.5	—	—	—	—	1.65	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	8.0	—	80.0	μA
	I _C	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω, input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
Propagation delay time	t _{pLH}	—		5.0 ± 0.5	—	9.9	14.5	1.0	16.5	ns
	t _{pHL}									
Input capacitance	C _{IN}	—		—	5	10	—	10	pF	
Power dissipation capacitance	C _{PD} (Note)	—		—	78	—	—	—	pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

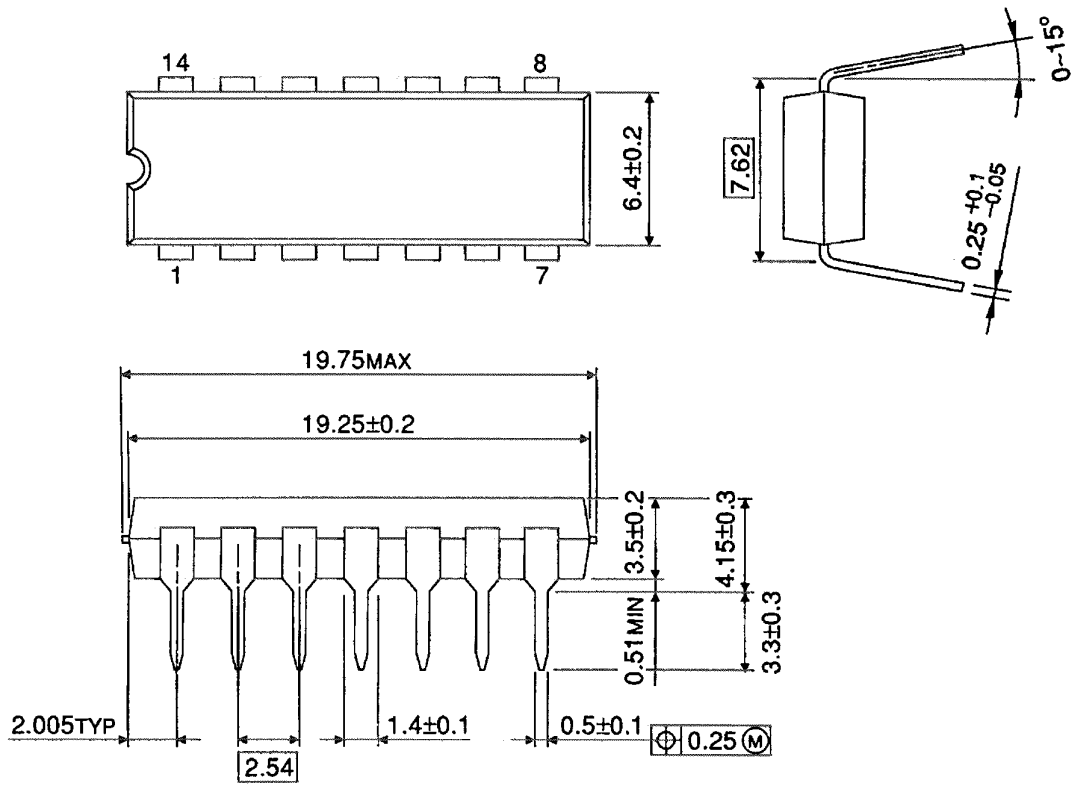
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

DIP14-P-300-2.54

Unit : mm

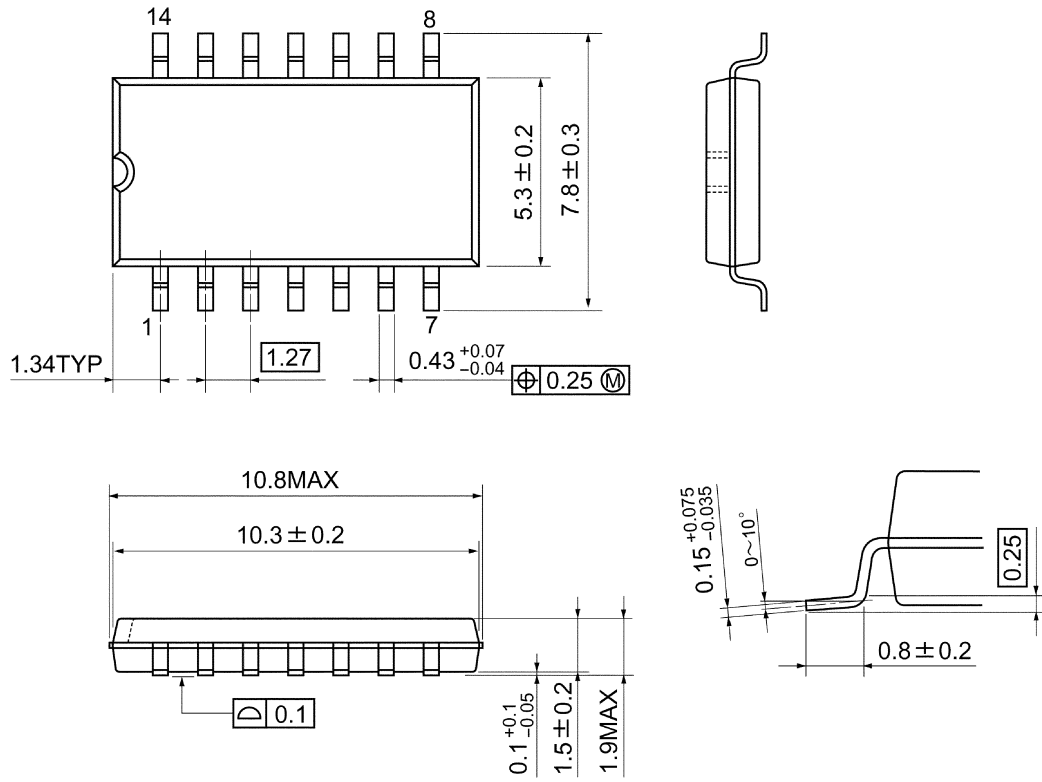


Weight: 0.96 g (typ.)

Package Dimensions

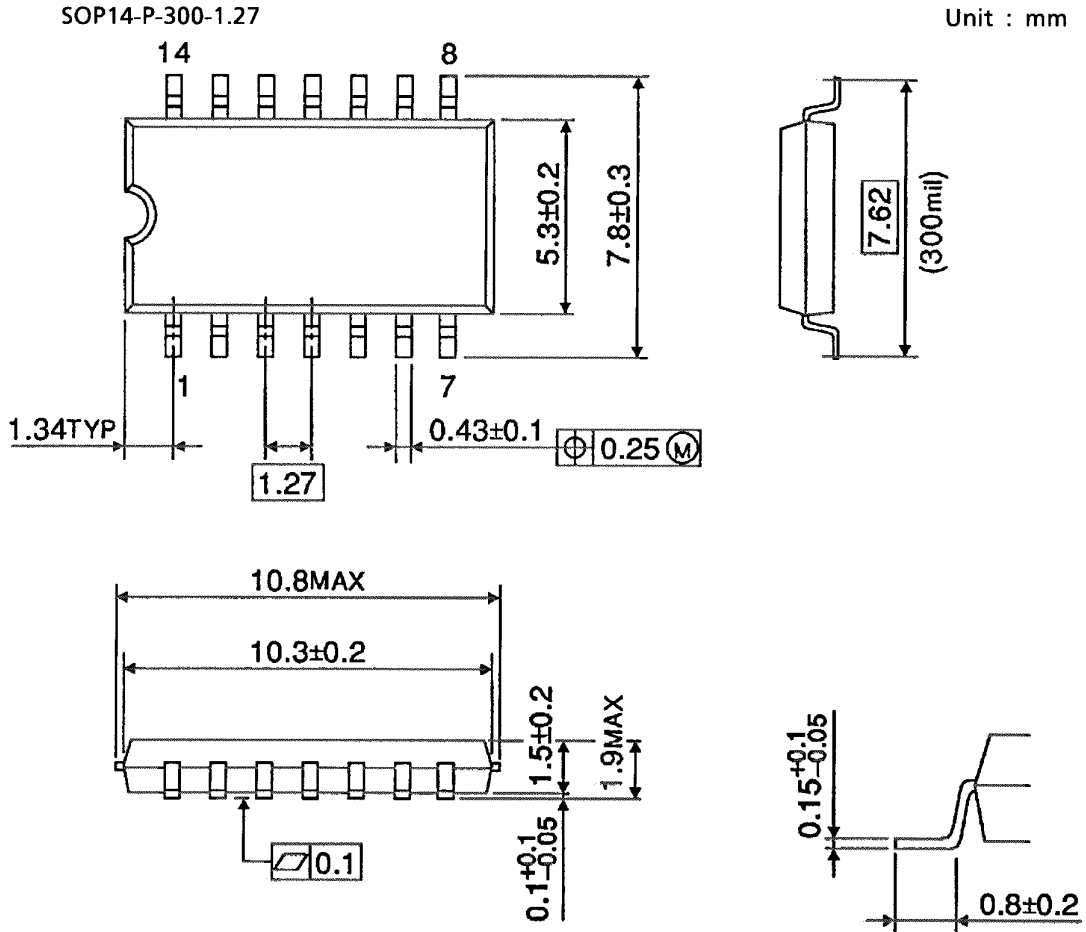
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

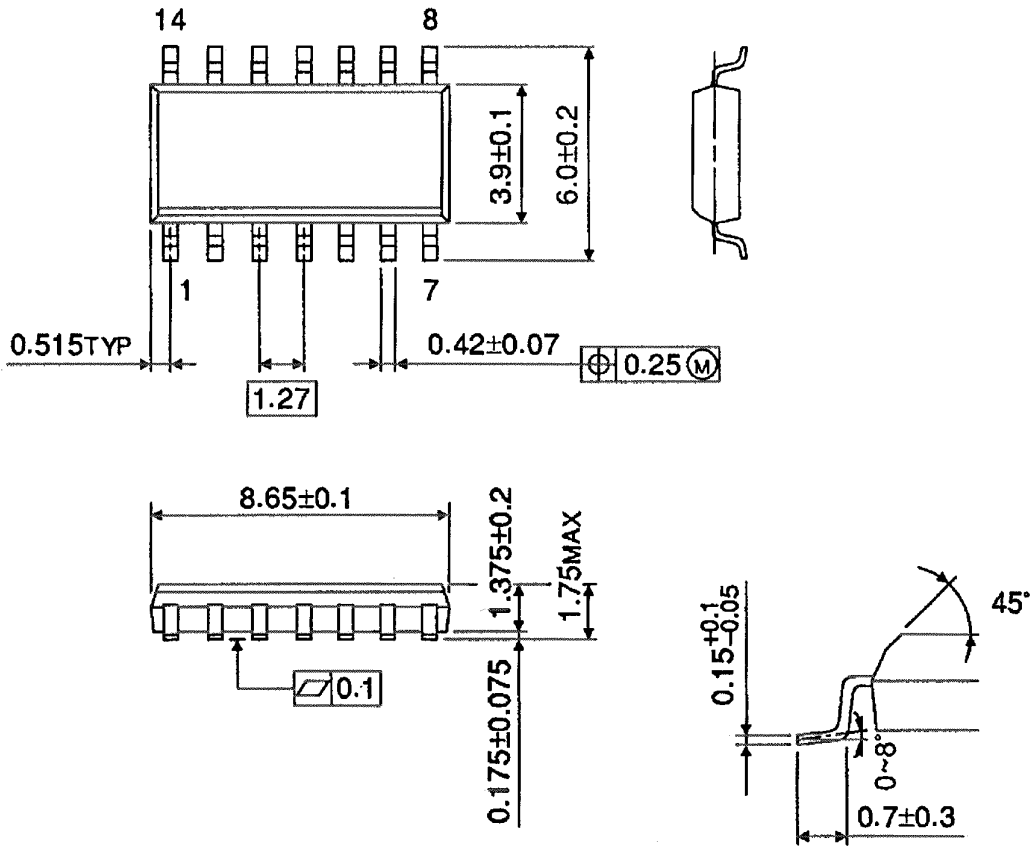


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages**DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27****RESTRICTIONS ON PRODUCT USE**

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